Rectifier diodes ultrafast, rugged

BYW29EX series

GENERAL DESCRIPTION

QUICK REFERENCE DATA

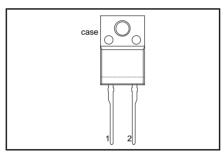
Glass passivated epitaxial rectifier diodes in a full pack plastic envelope, featuring low forward voltage drop, ultra-fast recovery times, soft recovery characteristic and guaranteed reverse surge and ESD capability. They are intended for use in switched mode power supplies and high frequency circuits in general where low conduction and switching losses are essential.

SYMBOL	PARAMETER	MAX.	MAX.	UNIT
V _{RRM} V _F I _{F(AV)} t _{rr} I _{RRM}	BYW29EX- Repetitive peak reverse voltage Forward voltage Forward current Reverse recovery time Repetitive peak reverse current	150 150 0.895 8 25 0.2	200 200 0.895 8 25 0.2	V V A ns A

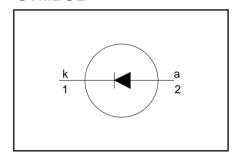
PINNING - SOD113

PIN	DESCRIPTION	
1	cathode	
2	anode	
case	isolated	

PIN CONFIGURATION



SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.		UNIT
V _{RRM} V _{RWM} V _R	Repetitive peak reverse voltage Crest working reverse voltage Continuous reverse voltage		1 1 1	-150 150 150 150	-200 200 200 200	< < <
I _{F(AV)}	Average forward current ¹	square wave; δ = 0.5; $T_{hs} \le 106 ^{\circ}\text{C}$ sinusoidal; a = 1.57; $T_{hs} \le 109 ^{\circ}\text{C}$	-		3	A A
I _{F(RMS)} I _{FRM}	RMS forward current Repetitive peak forward current		- -	11	.3 6	A A
I _{FSM}	Non-repetitive peak forward current	t = 10 ms t = 8.3 ms sinusoidal; with reapplied	-		0 8	A A
I ² t I _{RRM} I _{RSM}	I I'T for Tusing	$\begin{array}{l} V_{\text{RWM(max)}} \\ t = 10 \text{ ms} \\ t_{\text{p}} = 2 \mu\text{s}; \ \delta = 0.001 \\ t_{\text{p}} = 100 \mu\text{s} \end{array}$	- - -	0	2 .2 .2	A ² s A A
T_{stg} T_{j}	Storage temperature Operating junction temperature		-40 -		50 50	°C

¹ Neglecting switching and reverse current losses

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ESD LIMITING VALUE

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _C	l a	Human body model; C = 250 pF; R = 1.5 kΩ	-	8	kV

ISOLATION LIMITING VALUE & CHARACTERISTIC

T_{hs} = 25 °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{isol}	R.M.S. isolation voltage from both terminals to external heatsink	f = 50-60 Hz; sinusoidal waveform; R.H. ≤ 65%; clean and dustfree	1		2500	V
C _{isol}	Capacitance from both terminals to external heatsink	f = 1 MHz	-	10	-	pF

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{\text{th } j\text{-hs}}$ $R_{\text{th } j\text{-a}}$	heatsink	with heatsink compound without heatsink compound in free air		- - 55	5.5 7.2 -	K/W K/W

STATIC CHARACTERISTICS

 $T_i = 25$ °C unless otherwise stated

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V_{F}	Forward voltage	$I_F = 8 \text{ A}; T_i = 150^{\circ}\text{C}$	-	0.80	0.895	V
		$I_{\rm F} = 8 \text{A}$	-	0.92	1.05	V
		I _F = 20 A	-	1.1	1.3	V
l _R	Reverse current	$V_R = V_{RWM}$; $T_i = 100 ^{\circ}C$	-	0.2	0.6	mΑ
		$V_R = V_{RWM}$	-	2	10	μΑ

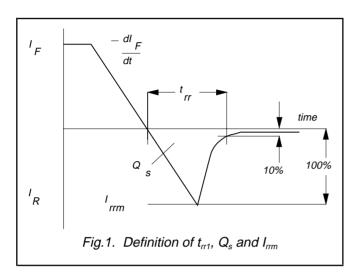
DYNAMIC CHARACTERISTICS

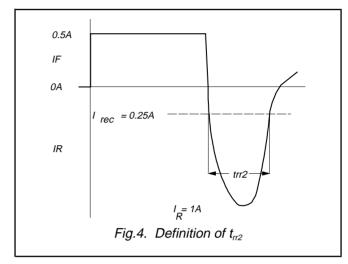
 $T_i = 25$ °C unless otherwise stated

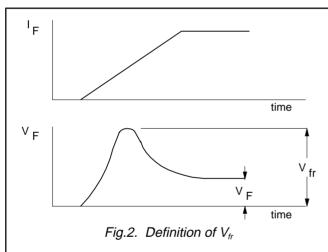
SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Q _s	Reverse recovery charge	$I_F = 2 \text{ A}; V_R \ge 30 \text{ V}; -dI_F/dt = 20 \text{ A/}\mu\text{s}$	-	4	11	nC
t _{rr1}	Reverse recovery time	$I_F = 1 \text{ A}; V_R \ge 30 \text{ V};$ - $dI_F/dt = 100 \text{ A/us}$	-	20	25	ns
$V_{\rm fr}$	Reverse recovery time Forward recovery voltage	$I_F = 0.5 \text{ A to } I_R = 1 \text{ A; } I_{rec} = 0.25 \text{ A}$ $I_F = 1 \text{ A; } dI_F/dt = 10 \text{ A/}\mu\text{s}$	-	15 1	20 -	ns V

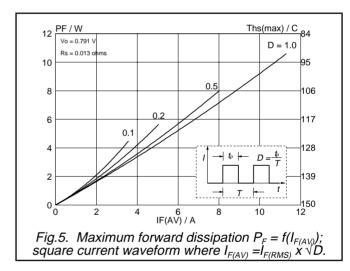
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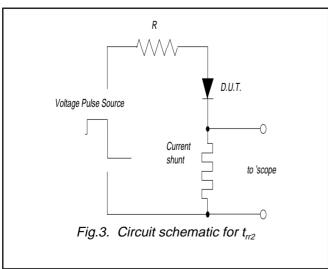
BYW29EX series

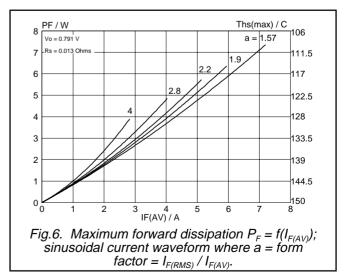






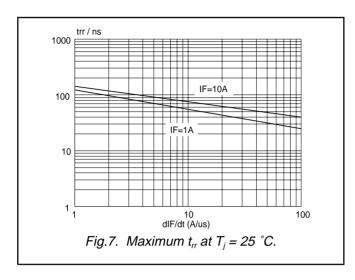


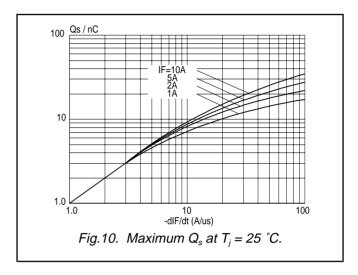


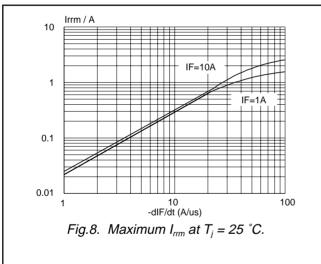


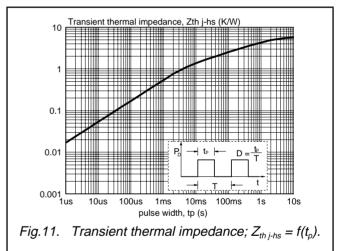
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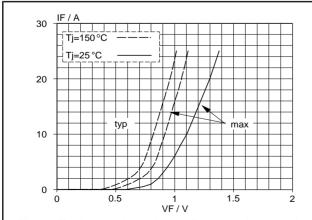
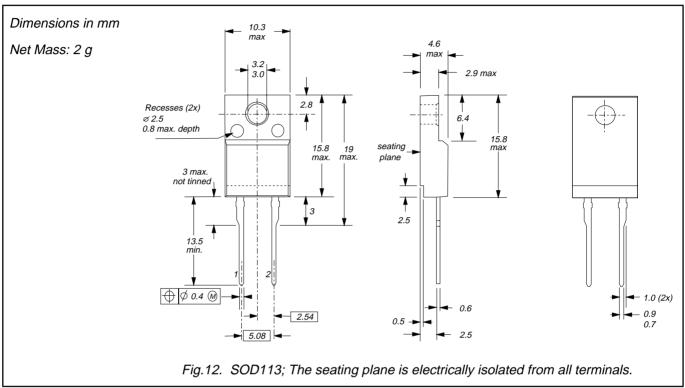


Fig.9. Typical and maximum forward characteristic $I_F = f(V_F)$; parameter T_j

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MECHANICAL DATA



Notes

- Refer to mounting instructions for F-pack envelopes.
 Epoxy meets UL94 V0 at 1/8".

Philips Semiconductors Product specification

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DEFINITIONS

Data sheet status					
Objective specification	This data sheet contains target or goal specifications for product development.				
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.				
Product specification	This data sheet contains final product specifications.				
Limiting values					

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

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